



# Product data sheet

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SS32C THRU SS310CHF

Semiconductor Compiance

#### **VOLTAGE RANGE**

20 to 100 Volts CURRENT 3.0 Ampere





- \* Ideal for surface mount applications
- \* Easy pick and place
- \* Built-in strain relief
- \* Low forward voltage drop

## **MECHANICAL DATA**

- \* Case: Molded plastic
- \* Epoxy: UL 94V-0 rate flame retardant
- \* Metallurgically bonded construction
- \* Polarity: Color band denotes cathode end
- \* Mounting position: Any
- \* Weight: 0.21 grams

# SMC

# MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature uniess otherwies specified. Single phase half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

P/N(MARK)	SS32C	SS33C	SS34C	SS35C	SS36C	SS38C	SS39C	SS310C	UNITS
Maximum Recurrent Peak Reverse Voltage		30	40	50	60	80	90	100	V
Maximum RMS Voltage		21	28	35	42	56	63	70	V
Maximum DC Blocking Voltage		30	40	50	60	80	90	100	V
Maximum Average Forward Rectified Current		•						•	
At T∟=100°C				3	.0				А
Peak Forward Surge Current, 8.3 ms single half sine-wa	ve								
superimposed on rated load (JEDEC method)				8	0				Α
Maximum Instantaneous Forward Voltage at 3.0A		0.55 0.70		0.85		V			
Maximum DC Reverse Current Ta=25°C		0.1 0.02			mA				
at Rated DC Blocking Voltage Ta=100°C			5				2		mA
Typical Junction Capacitance (Note1) 300				pF					
Typical Thermal Resistance R JL (Note 2)		10					°C/W		
Operating Temperature Range TJ		-65 -+ + 150					°C		
Storage Temperature Range Tstg		-65-+150			Ĵ				

NOTES:

1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal Resistance Junction to Lead.



#### RATING AND CHARACTERISTIC CURVES (SS32C THRU SS310C)

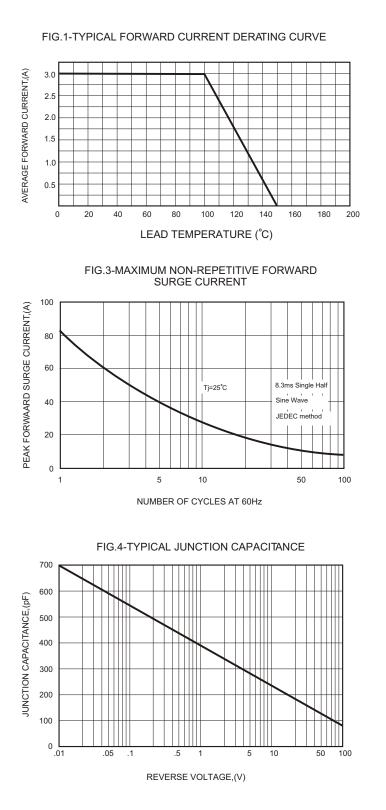


FIG.2-TYPICAL FORWARD

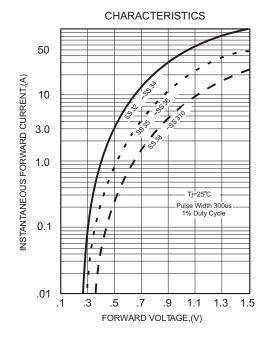
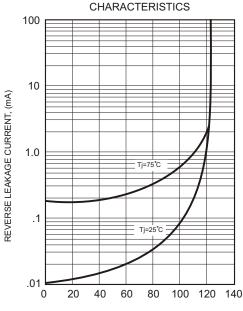


FIG.5 - TYPICAL REVERSE



PERCENTAGE RATED PEAK REVERSE VOLTAGE

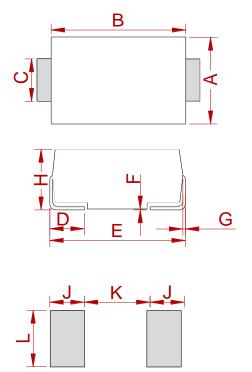


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ROHS

## PACKAGE MECHANICAL DATA



	Dimensions				
Ref.	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
A	5.75	6.25	0.226	0.246	
В	6.90	7.40	0.272	0.291	
С	2.75	3.25	0.108	0.128	
D	0.95	1.52	0.037	0.060	
E	7.70	8.20	0.303	0.323	
F	0.051	0.203	0.002	0.008	
G	0.15	0.31	0.006	0.012	
Н	2.15	2.62	0.085	0.103	
J	2.40		0.094		
К		4.20		0.165	
L	3.30		0.130		

SMC

### **REEL SPECIFICATION**

P/N	PKG	QTY
SS32C THRU SS310C	SMC	3000



<u>SS32C THRU SS310C HF</u> 🐼

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